PHYSICAL REVIEW B **THIRD SERIES, VOLUME 56, NUMBER 3** **15 JULY 1997-I**

Resonant Faraday rotation in a semiconductor microcavity 1087
A. V. Kavokin, M. R. Vladimirova, M. A. Kaliteevski, O. Lyngnes, J. D. Berger, H. M. Gibbs, and G. Khitrova

Surface physics, low-dimensional systems, and related topics

Structure and stability of cluster-assembled solid $Al_{12}C(Si)$: A first-principles study 1091
X. G. Gong
Stress sum rules for the flat surface of stabilized jellium 1095
A. Kiejna and P. Ziesche
Femtosecond photoemission study of ultrafast electron dynamics on Cu(100) 1099
J. Cao, Y. Gao, R. J. D. Miller, H. E. Elsayed-Ali, and D. A. Mantell
Competition between Anderson localization and leakage of surface-plasmon polaritons on randomly rough periodic metal surfaces 1103
J. A. Sánchez-Gil and A. A. Maradudin
Nonlinear photoemission from W and Cu investigated by total-yield correlation measurements 1107
A. Bartoli, G. Ferrini, L. Fini, G. Gabetta, F. Parmigiani, and F. T. Arecchi
Angle-resolved resonant photoemission at the M_{III} absorption threshold of Co and Fe metal 1111
A. Gutiérrez and M. F. López

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Exchange and correlation corrections to the response functions of a spin-polarized electron gas 1114
D. C. Marinescu and J. J. Quinn
Functional theory of extended Coulomb systems 1124
Richard M. Martin and Gerardo Ortiz
Optical conductivity of the Hubbard model 1141
J. J. Vicente Alvarez, C. A. Balseiro, and H. A. Ceccatto
Mott-Hubbard insulators for systems with orbital degeneracy 1146
Olle Gunnarsson, Erik Koch, and Richard M. Martin
Exact Fermi-edge singularity exponent in a Luttinger liquid 1153
Andrei Komnik, Reinhold Egger, and Alexander O. Gogolin
Screening of the Coulomb interaction in two-dimensional variable-range hopping 1161
F. W. Van Keuls, X. L. Hu, H. W. Jiang, and A. J. Dahm
Electronic transport for random dimer-trimer model Hamiltonians 1170
Riccardo Farchioni and Giuseppe Grosso
Charge-density waves and density of states in the intercalated tunnel structure $Tl_xNb_3Te_4$ 1175
F. W. Boswell, G. A. Scholz, and J. C. Bennett
Subpicosecond vibronic dynamics in KBr *F* centers 1179
Reinhard Scholz, Michael Schreiber, Franco Bassani, Mauro Nisoli, Sandro De Silvestri, and Orazio Svelto
Slave-boson mean-field theory of the antiferromagnetic state in the doubly degenerate Hubbard model: The half-filled case 1196
Hideo Hasegawa
Frequency and voltage dependence of the complex shear compliance of TaS_3: A relaxation analysis 1204
X. Zhan and J. W. Brill
Truncation method for Green's functions in time-dependent fields 1213
Tobias Brandes
Origin of thermal fixing in photorefractive lithium niobate crystals 1225
K. Buse, S. Breer, K. Peithmann, S. Kapphan, M. Gao, and E. Krätzig

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 56, NUMBER 3** **15 JULY 1997-I**

Percolation exponents and thresholds obtained from the nearly ideal continuum percolation system graphite-boron nitride 1236
Junjie Wu and D. S. McLachlan

Transport coefficients in random two-phase media with interfacial resistance 1249
Giorgio Zoia and William Strieder

Site-selective spectroscopy of Tb^{3+} centers in SrF_2 and CaF_2 1254
K. M. Murdoch, G. D. Jones, and R. W. G. Syme

STM-induced luminescence study of poly(p-phenylenevinylene) by conversion under ultraclean conditions 1269
Santos F. Alvarado, Walter Rieß,, Paul F. Seidler, and Peter Strohriegl

Resonant soft-x-ray inelastic scattering from Gd in the $Gd_3Ga_5O_{12}$ garnet with excitation across the M_5 edge 1279
C. Dallera, L. Braicovich, G. Ghiringhelli, M. A. van Veenendaal, J. B. Goedkoop, and N. B. Brookes

Soft-x-ray emission and absorption study of the quasi-one-dimensional oxide conductors $K_{0.3}MoO_3$ and $Li_{0.9}Mo_6O_{17}$ 1284
L.-C. Duda, J. H. Guo, J. Nordgren, C. B. Stagarescu, K. E. Smith, W. McCarroll, K. Ramanujachary, and M. Greenblatt

Electronic structure and magnetic states in $La_{1-x}Sr_xCoO_3$ studied by photoemission and x-ray-absorption spectroscopy 1290
T. Saitoh, T. Mizokawa, A. Fujimori, M. Abbate, Y. Takeda, and M. Takano

Critical indices in a $d=1$ filled-band Fermi system 1296
F. Bonetto and V. Mastropietro

Electron-momentum spectroscopy of fullerene 1309
M. Vos, S. A. Canney, I. E. McCarthy, S. Utteridge, M. T. Michalewicz, and E. Weigold

Solution of the effective Hamiltonian of impurity hopping between two sites in a metal 1316
Jinwu Ye

Interplay between dynamic screened f-f interaction and $\mathbf{s_k}\cdot\mathbf{s}_f$ interaction in Ce systems 1335
F. López-Aguilar, J. Costa-Quintana, and M. M. Sánchez-López

Electrical transport, magnetism, and magnetoresistance in ferromagnetic oxides with mixed exchange interactions: A study of the $La_{0.7}Ca_{0.3}Mn_{1-x}Co_xO_3$ system 1345
N. Gayathri, A. K. Raychaudhuri, S. K. Tiwary, R. Gundakaram, Anthony Arulraj, and C. N. R. Rao

Ab initio study of lithium intercalation in metal oxides and metal dichalcogenides 1354
M. K. Aydinol, A. F. Kohan, G. Ceder, K. Cho, and J. Joannopoulos

Semiconductors I: bulk

Low-temperature transport, optical, magnetic and thermodynamic properties of $Fe_{1-x}Co_xSi$ 1366
M. A. Chernikov, L. Degiorgi, E. Felder, S. Paschen, A. D. Bianchi, H. R. Ott, J. L. Sarrao, Z. Fisk, and D. Mandrus

Si:Au and Si:Pt $1S_{3/2}(\Gamma_8)+\Gamma$ phonon-assisted Fano resonance 1376
M. Kleverman, J. Olajos, and P. Tidlund

Anharmonic interactions in bonds between impurities and host atoms in GaAs:C and GaAs:B 1381
D. A. Robbie, R. S. Leigh, and M. J. L. Sangster

Defects in silicon after B^+ implantation: A study using a positron-beam technique, Rutherford backscattering, secondary neutral mass spectroscopy, and infrared absorption spectroscopy 1393
S. Eichler, J. Gebauer, F. Börner, A. Polity, R. Krause-Rehberg, E. Wendler, B. Weber, W. Wesch, and H. Börner

Electronic properties of polygonal defects in graphitic carbon sheets 1404
Ryo Tamura, Kazuto Akagi, Masaru Tsukada, Satoshi Itoh, and Sigeo Ihara

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 56, NUMBER 3** **15 JULY 1997-I**

Semiconductors II: surfaces, interfaces, microstructures, and related topics

The reconstruction of the Si(110) surface and its interaction with Si adatoms 1412
Madhu Menon, Nectarios N. Lathiotakis, and Antonis N. Andriotis
Photovoltaic study of ZnSe/GaAs heterostructures 1416
J. B. Wang, D. Y. Chen, C. X. Jin, F. Lu, H. H. Sun, and X. Wang
Localization and conductance fluctuations in the integer quantum Hall effect: Real-space renormalization-group approach 1422
A. G. Galstyan and M. E. Raikh
Low-frequency plasmons in metallic carbon nanotubes 1430
M. F. Lin, D. S. Chuu, and K. W.-K. Shung
Stability of classical electron orbits in triangular electron billiards 1440
H. Linke, L. Christensson, P. Omling, and P. E. Lindelof
Magnetoquantum effects in III-V tunneling heterostructures 1447
K. S. Chan, F. W. Sheard, G. A. Toombs, and L. Eaves
Anisotropy of zero-bias diffusive anomalies for different orientations of an external magnetic field 1456
E. V. Sukhorukov and A. V. Khaetskii
Invariant structure of the hierarchy theory of fractional quantum Hall states with spin 1461
M. Milovanović and N. Read
Evidence of internal electric fields in $GaInP_2$ by scanning capacitance and near-field scanning optical microscopy 1472
J-K. Leong, C. C. Williams, and J. M. Olson
Effect of vertical transport on superlattice luminescence in the presence of an in-plane magnetic field 1479
V. F. Aguekian, B. S. Monozon, C. A. Bates, J. L. Dunn, T. Komatsu, N. Miura, and K. Uchida
Electronic confinement in a single GaAs quantum well probed by low-frequency resonant Raman scattering 1486
A. Mlayah, A. Sayari, R. Grac, A. Zwick, R. Carles, M. A. Maaref, and R. Planel
Optical properties of $GaN/Al_xGa_{1-x}N$ quantum wells 1491
R. Cingolani, G. Coli', R. Rinaldi, L. Calcagnile, H. Tang, A. Botchkarev, W. Kim, A. Salvador, and H. Morkoç
InP quantum dots: Electronic structure, surface effects, and the redshifted emission 1496
Huaxiang Fu and Alex Zunger
Optical properties of $GaAs/Al_xGa_{1-x}As$ quantum wells disordered by ion implantation 1509
I. Shtrichman, D. Gershoni, and R. Kalish
Coupling between LO phonons and electronic excitations of quantum dots 1516
P. A. Knipp, T. L. Reinecke, A. Lorke, M. Fricke, and P. M. Petroff
Electron mobility in $Al_xGa_{1-x}N/GaN$ heterostructures 1520
L. Hsu and W. Walukiewicz

Surface physics, low-dimensional systems, and related topics

Multiple energy x-ray holography: Incident-radiation polarization effects 1529
P. M. Len, T. Gog, D. Novikov, R. A. Eisenhower, G. Materlik, and C. S. Fadley
Angle-resolved photoemission extended fine structure of the Ni $3p$, Cu $3s$, and Cu $3p$ core levels of the respective clean (111) surfaces 1540
W. R. A. Huff, Y. Chen, S. A. Kellar, E. J. Moler, Z. Hussain, Z. Q. Huang, Y. Zheng, and D. A. Shirley
Directional effects during ion implantation: Lateral mass transport and anisotropic growth 1551
M. Chicoine, S. Roorda, L. Cliche, and R. A. Masut
Coverage dependence of surface structure and vibration of Cl/Cu(100) compared to Cl/Ni(100) 1561
M. Kiguchi, T. Yokoyama, S. Terada, M. Sakano, Y. Okamoto, T. Ohta, Y. Kitajima, and H. Kuroda
Molecular-dynamics study of diamond/silicon (001) interfaces with and without graphitic interface layers 1568
M. Sternberg, W. R. L. Lambrecht, and Th. Frauenheim

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 56, NUMBER 3** **15 JULY 1997-I**

Equilibrium configuration of atomic steps on vicinal Si(001) surfaces with external biaxial strain 1581
C. Ebner, D. E. Jones, and J. P. Pelz
Grazing-ion-surface interaction as a probe of surface states 1589
Q. Yan, J. Burgdörfer, and F. W. Meyer
High-resolution photoemission from a tunable quantum well: Cu(111)/Na 1593
A. Carlsson, B. Hellsing, S.-Å. Lindgren, and L. Walldén
Experimental study of surface-plasmon scattering by individual surface defects 1601
Igor I. Smolyaninov, David L. Mazzoni, Joseph Mait, and Christopher C. Davis
Quantitative model of electron energy loss in XPS 1612
A. Cohen Simonsen, F. Yubero, and S. Tougaard
Surface and bulk $4f$-photoemission spectra of $CeIn_3$ and $CeSn_3$ 1620
H.-D. Kim, O. Tjernberg, G. Chiaia, H. Kumigashira, T. Takahashi, L. Duò, O. Sakai, M. Kasaya, and I. Lindau
Ab initio study of $BaTiO_3$ surfaces 1625
J. Padilla and David Vanderbilt
Picosecond spectroscopy and hyperlinear photoluminescence in poly(para-phenylene)-type ladder polymers 1632
G. Kranzelbinder, H. J. Byrne, S. Hallstein, S. Roth, G. Leising, and U. Scherf

Errata

Erratum: Evolution of the interband absorption threshold with the density of a two-dimensional electron gas [Phys. Rev. B **54**, R11 082 (1996)] 1637
S. A. Brown, Jeff F. Young, J. A. Brum, P. Hawrylak, and Z. Wasilewski
Erratum: Two-dimensional excitonic emissions in InAs submonolayers [Phys. Rev. B **54**, 16 919 (1996)] 1637
Z. L. Yuan, Z. Y. Xu, B. Z. Zheng, J. Z. Xu, S. S. Li, W. K. Ge, Y. Wang, J. Wang, and L. L. Chang
Erratum: Anomalous strong repulsive step-step interaction on slightly misoriented Si(113) [Phys. Rev. B **55**, 7864 (1997)] 1638
S. van Dijken, H. J. W. Zandvliet, and Bene Poelsema

Cumulative Author Index 1639